

20V PNP HIGH GAIN TRANSISTOR IN SOT89

Features

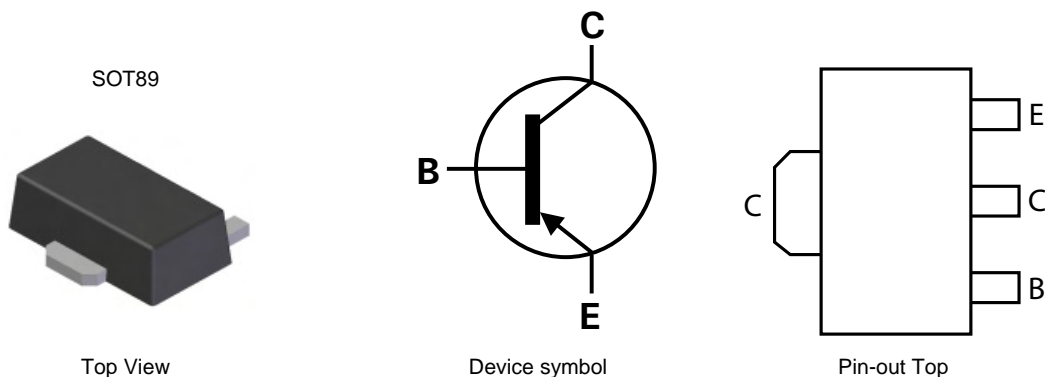
- $BV_{CEO} > -20V$
- High current capability Max Continuous Current $I_C = -6A$
- Low saturation voltage $V_{CE(sat)} < -47mV @ I_C = -1A$
- $R_{CE(sat)} = 28m\Omega$
- $P_D = 2.4W$
- Complementary part number ZXTN19020DZ
- **Lead Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free, "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT89
- Moisture Sensitivity: Level 1 per J-STD-020
- UL Flammability Rating 94V-0
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)

Application

- Power disconnect switch
- Battery chargers
- High side drivers
- Motor drive

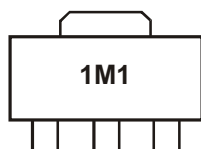


Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP19020DZTA	1M1	7	12	1,000

- Notes:
1. No purposefully added lead.
 2. Halogen and Antimony Free. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, go to our website at <http://www.diodes.com>

Marking Information



1M1 = Product Type Marking Code

Maximum Ratings @T_A = 25°C unless otherwise specified

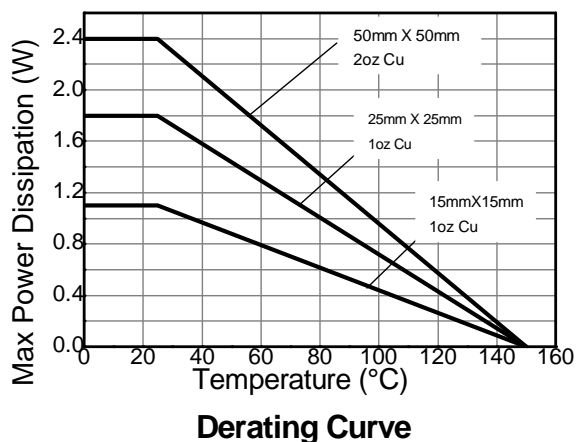
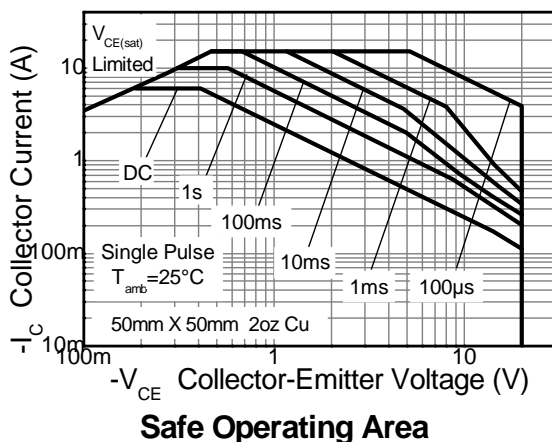
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-25	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{ECO}	-4	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current (Note 6)	I _C	-6	A
Base current	I _B	-1	A
Peak Pulse Current	I _{CM}	-15	A

Thermal Characteristics @T_A = 25°C unless otherwise specified

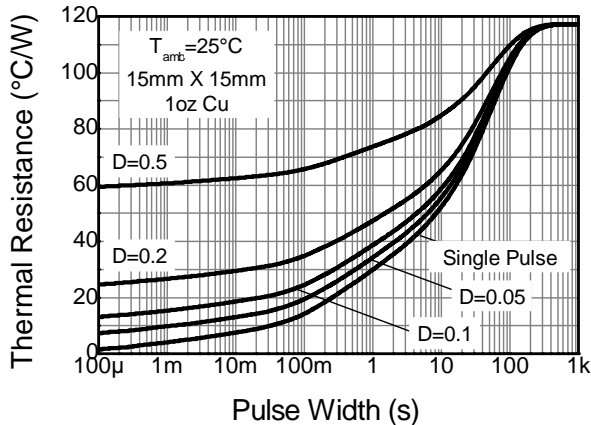
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P _D	1.1	W
Linear derating factor		8.8	mW/°C
Power Dissipation (Note 5)	P _D	1.8	W
Linear derating factor		14.4	mW/°C
Power Dissipation (Note 6)	P _D	2.4	W
Linear derating factor		19.2	mW/°C
Power Dissipation (Note 7)	P _D	4.46	W
Linear derating factor		35.7	mW/°C
Power Dissipation (Note 8)	P _D	26.7	W
Linear derating factor		213	mW/°C
Thermal Resistance, Junction to Ambient (Note 4)	R _{θJA}	117	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	68	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	51	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _{θJA}	117	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R _{θJL}	4.69	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
- For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 - Mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 - Mounted on 50mm x 50mm x 0.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.
 - As note 6 above measured at t<5 seconds.
 - Junction to case (collector tab). Typical

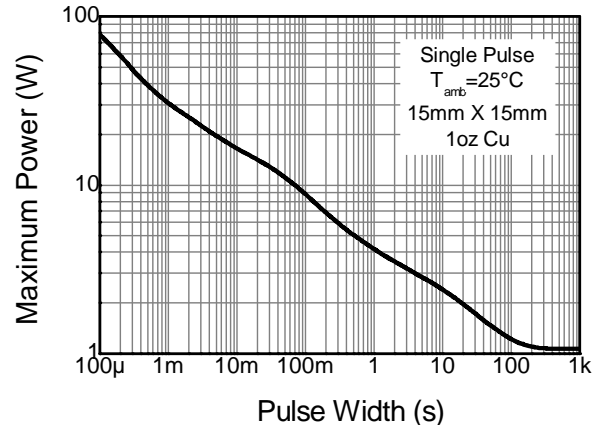
Thermal Characteristics



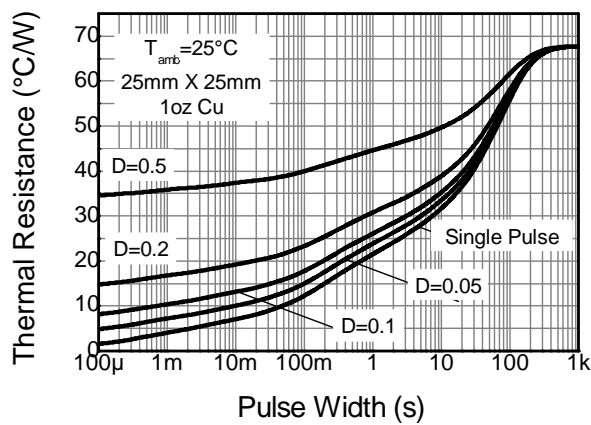
Thermal Characteristics (- Continued)



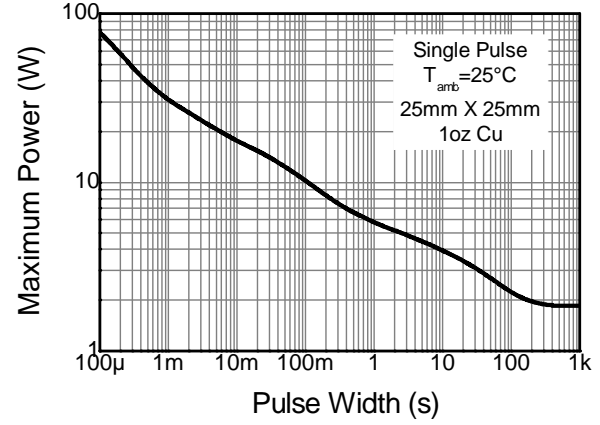
Transient Thermal Impedance



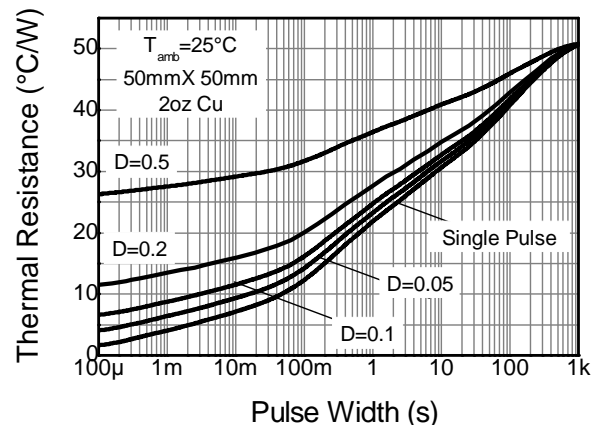
Pulse Power Dissipation



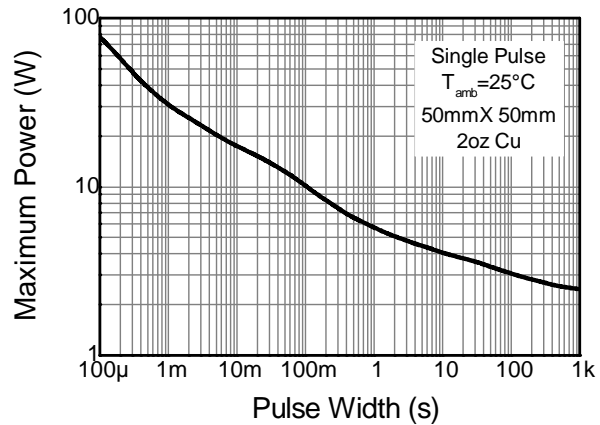
Transient Thermal Impedance



Pulse Power Dissipation



Transient Thermal Impedance



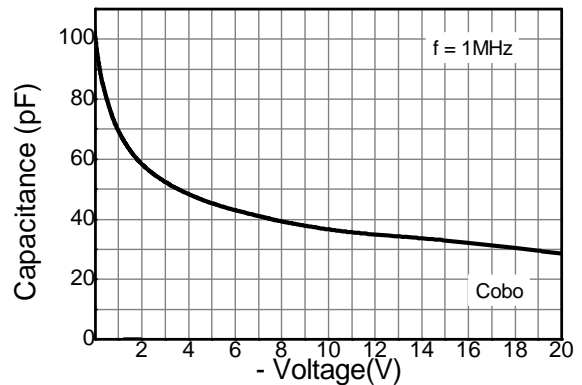
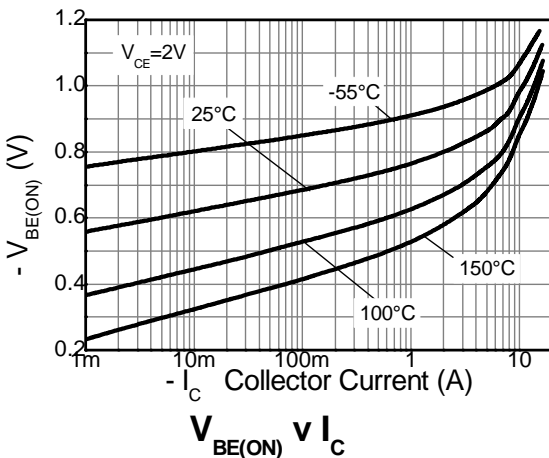
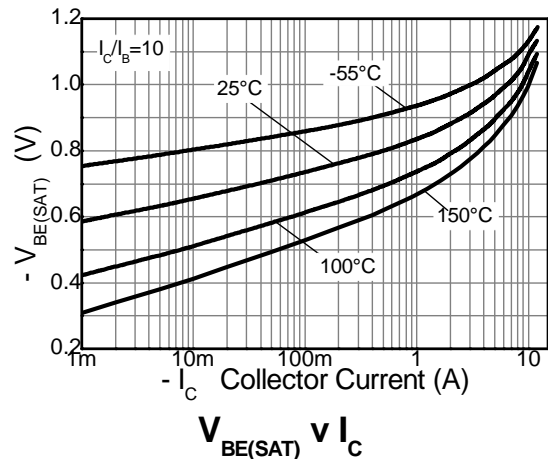
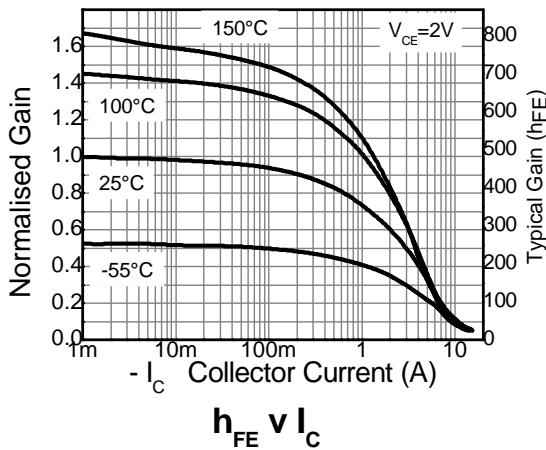
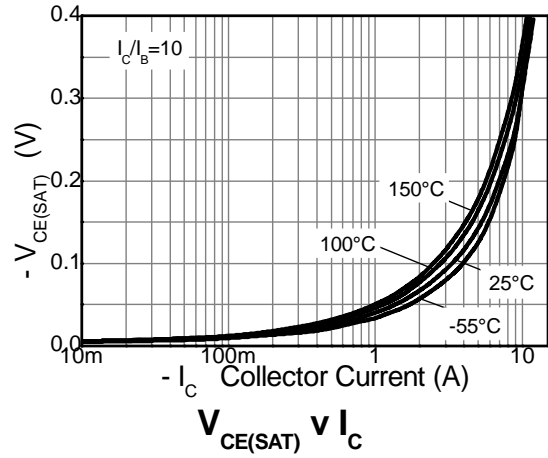
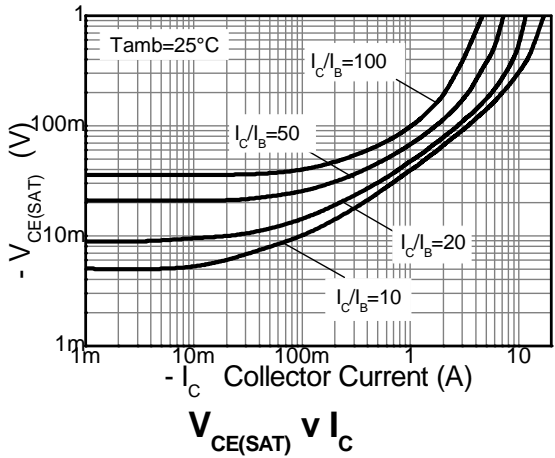
Pulse Power Dissipation

Electrical Characteristics @T_A = 25°C unless otherwise specified

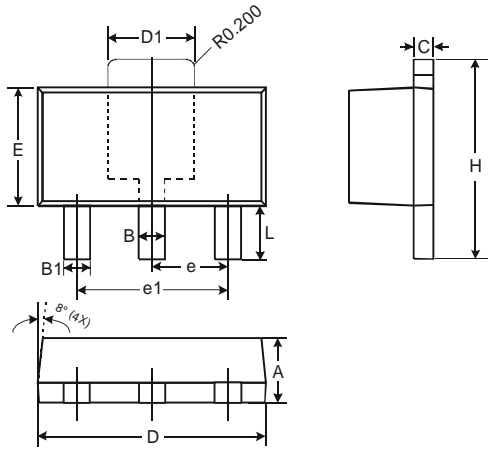
Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CB0}	-25	-55	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Notes 9)	BV _{CEO}	-20	-50	-	V	I _C = -10mA
Emitter-Collector breakdown voltage (reverse blocking)	BV _{ECX}	-4	-8.6	-	V	I _E = -100μA, R _{BC} < 1kΩ or 0.25V > V _{BC} > -0.25V
Emitter-Collector breakdown voltage (reverse blocking)	BV _{ECO}	-4	-8.6	-	V	I _E = -100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.2	-	V	I _E = -100μA
Collector Cutoff Current	I _{CB0}	-	< -1	-50	nA	V _{CB} = -25V
		-	-	-500		V _{CB} = -25V, T _A = 100°C
Emitter Cutoff Current	I _{EBO}	-	< -1	-50	nA	V _{EB} = -5.6V
DC current transfer Static ratio (Notes 9)	h _{FE}	300	450	900	-	I _C = -100mA, V _{CE} = -2V
		200	290	-		I _C = -2A, V _{CE} = -2V
		65	110	-		I _C = -6A, V _{CE} = -2V
		-	25	-		I _C = -15A, V _{CE} = -2V
Collector-Emitter Saturation Voltage (Notes 9)	V _{CE(sat)}	-	-40	-47	mV	I _C = -1A, I _B = -100mA
		-	-100	-130		I _C = -1A, I _B = -10mA
		-	-115	-145		I _C = -2A, I _B = -40mA
		-	-225	-275		I _C = -6A, I _B = -300mA
Base-Emitter Saturation Voltage (Notes 9)	V _{BE(sat)}	-	-1000	-1100	mV	I _C = -6A, I _B = -300mA
Base-Emitter Turn-on Voltage (Notes 9)	V _{BE(on)}	-	-865	-1000	mV	I _C = -6A, V _{CE} = -2V
Transitional Frequency (Notes 9)	f _T	-	176	-	MHz	I _C = -50mA, V _{CE} = -10V, f = 50MHz
Input Capacitance	C _{ibo}	-	-	400	pF	V _{EB} = -0.5V, f = 1MHz
Output capacitance	C _{obo}	-	36	45	pF	V _{CB} = -10V, f = 1MHz
Delay time	t _d	-	23	-	ns	V _{CC} = -10V, I _C = -1A, I _{B1} = -I _{B2} = -50mA
Rise time	t _r	-	18.4	-	ns	
Storage time	t _s	-	266	-	ns	
Fall time	t _f	-	49.6	-	ns	

Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics

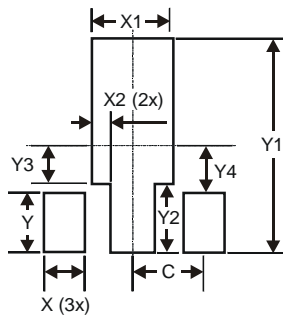


Package Outline Dimensions



SOT89		
Dim	Min	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.43
D	4.40	4.60
D1	1.52	1.83
E	2.29	2.60
e	1.50 Typ	
e1	3.00 Typ	
H	3.94	4.25
L	0.89	1.20
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А